

On the characterization of MPA CVD diamond for fracture toughness measurements

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Methods

Double Torsion

Machine head, Sample, Limiters (3), Balls, Sample base, Machine base, Grub screws (3)

$$K = P S_m \left(\frac{3}{S t^4 (1 - \nu) \psi} \right)^{1/2}$$

Load, P, Precrack, Specimen, Notch, S, L, t, S_m

Failure to fracture in diamond disks: Fracture toughness & Integrity assessment

60 ITER disks, Ø70 mm, 1.11 mm

Brazing region, Aperture region

322 µm, 447 µm, GS, NS

~ 300 µm deep

Torus side Disk GS, Gyrotron side Disk NS, Disk, Stiffening ring, Cuff, NO + 2 bar

Symmetry Region, Fixed Support, Disk growth side (GS), Degraded CuCrZr, CVD diamond, Pure copper

Ø80 mm disk, optical

15 mm x 30 mm x 1.11 mm

µm

- [100 : 150]
- [150 : 200]
- [200 : 250]
- [250 : 300]
- [300 : 600]

Microscopy, EBSD, Raman, Loss tangent, XRD, Pillar splitting

from Ø150 mm disk, thermal

10 mm

Preliminary optical (GS), Preliminary thermal (GS)

12 mm x 22 mm x 1.11 mm

Results

Microfeatures - 24 disks

33%, 42%, 25%

S-T30, S-T02, S-T19

$\rho_{\text{micr.,braz.}} / \rho_{\text{micr.,aper.}} < 3$, $\rho_{\text{micr.,braz.}} / \rho_{\text{micr.,aper.}} > 20$

Optical, XRD sin²ψ method

Φ (°)	GS σ (MPa)	NS σ (MPa)
0	74.7 ± 112	-8.8 ± 47.9
45	-114 ± 88.7	93.9 ± 45.9
90	-84.6 ± 110	-67.5 ± 34.6

Disk GS

Aperture boundary, Brazing boundaries, ~37 MPa, ~48 MPa, ~84 MPa, ~56 MPa

σ₀ ~ 84 MPa, a ~ 320 µm, β ~ 1 (rough estimation), K_I ~ 2.6 MPa m^{1/2}, K_{IC} ~ 8 MPa m^{1/2} (Davies, J. Mater. Sci, 2004)

Number of microfeatures in brazing region

Disk/Ranges [µm]	100 - 150	150 - 200	200 - 250	250 - 300	300 - 600
S-T02	534	121	31	6	1
S-T03	299	53	12	4	1
S-T04	94	17	7	5	1
S-T05	447	82	21	7	0
S-T06	25	17	9	5	0
S-T17	1213	400	171	53	26
S-T09	326	71	11	4	2
S-T12	257	94	24	10	5
S-T08	164	27	15	10	1
S-T10	108	14	6	0	0
S-T13	82	13	4	2	1
S-T15	482	142	42	22	7
S-T16	80	10	1	1	0
S-T19	1422	580	255	102	64
S-T21	332	73	18	7	3
S-T23	1153	424	136	63	28
S-T14	264	69	14	4	1
S-T20	268	80	38	15	9
S-T24	1008	365	127	45	36
S-T27	452	101	27	4	1
S-T28	809	228	83	22	6
S-T30	40	15	6	10	1
S-T31	62	19	6	2	1
S-T33	85	21	6	0	1
Average	417	127	45	17	8

GS - grain size

Average by number ~ 50 µm, Average by area ~ 200 µm

NS - grain size

Average by number ~ 6 µm, Average by area ~ 9 µm

Laser cut from side

Laser cut from top

Finalize experimental setup design for manufacturing, complete microscopy activity for ITER disks, characterize real-size samples